TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HCT374AP,TC74HCT374AF

Octal D-Type Flip-Flop with 3-State Output

The TC74HCT374A is high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

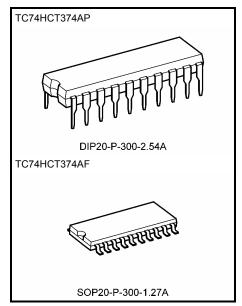
Their inputs are compatible with TTL, NMOS, and CMOS output voltage levels.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}).

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

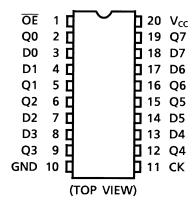
- High speed: $f_{max} = 62 \text{ MHz (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs: $V_{IH} = 2 V (min)$ $V_{IL} = 0.8 V (max)$
- Wide interfacing ability: LSTTL, NMOS, CMOS
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 6 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- · Pin and function compatible with 74LS374



Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.)

Pin Assignment



IEC Logic Symbol

OE (1) CK (11)	EN > C1	
D0 (3) D1 (4) D2 (7) D3 (8) D4 (13) D5 (14) D6 (17) D7 (18)	1D	(2) Q0 (5) Q1 (6) Q2 (9) Q3 (12) Q4 (15) Q5 (16) Q6 (19) Q7

Truth Table

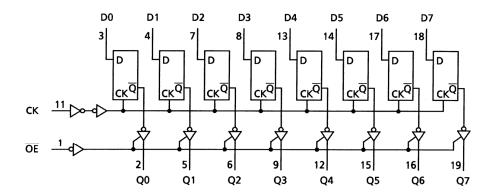
	Output		
ŌE	CK	D	Q
Н	Х	Х	Z
L	\neg	Х	Qn
L		L	L
L		Н	Н

X: Don't care

Z: High impedance

Q_n: No change

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	Vout	-0.5~V _{CC} + 0.5	V
Input diode current	ΙιΚ	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±35	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5~5.5	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	t _r , t _f	0~500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test Condition V _{CC} (V)		Ta = 25°C			Ta = -4	Unit		
				V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
High-level input voltage	V _{IH}	_		4.5~5.5	2.0	ı	ı	2.0	_	V
Low-level input voltage	V_{IL}		_	4.5~5.5	ı	ı	0.8	_	0.8	٧
High-level output	V _{OH}	V _{IN}	$I_{OH} = -20 \ \mu A$	4.5	4.4	4.5	-	4.4	_	V
voltage	VOH	$= V_{IH} \text{ or } V_{IL}$	$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31		4.13	_	٧
Low-level output	V _{OL}		$I_{OL}=20~\mu A$	4.5		0.0	0.1		0.1	V
voltage	VOL	$= V_{IH}$ or V_{IL}	$I_{OL} = 6 \text{ mA}$	4.5		0.17	0.26		0.33	٧
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5			±0.5		±5.0	μΑ
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5			±0.1	_	±1.0	μΑ
Quiescent supply	I _{CC}	$V_{IN} = V_{CC}$ or	GND	5.5		_	4.0	_	40.0	μΑ
current	I _C	Per input: V _{II} Other input:	$_{N}$ = 0.5 V or 2.4 V $_{CC}$ or GND	5.5		_	2.0	_	2.9	mA



Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = −40 ~85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	tw (H)		4.5	_	15	19	no
(CK)	t _{W (L)}	_	5.5	_	14	17	ns
Minimum set-up time			4.5	_	15	19	no
(Dn)	ts	_	5.5	_	14	17	ns
Minimum hold time	4.		4.5	_	0	0	no
(Dn)	t _h	_	5.5	_	0	0	ns
Clask fraguency	f		4.5	_	31	25	MHz
Clock frequency	ļ		5.5		37	30	IVI⊓Z

AC Characteristics (input: $t_r = t_f = 6$ ns)

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = -40~85°C		Unit		
Characteristics	Symbol		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic	
Output transition time	t _{TLH}		50	4.5	_	7	12	_	15	ns	
Output transition time	t _{THL}	_	30	5.5		6	11	_	14	115	
			50	4.5	_	20	30	_	38		
Propagation delay time	t _{pLH}		30	5.5		17	25	_	31	ns	
(CK-Q)	t_{pHL}	_	150	4.5		25	38	_	48	113	
			130	F) V _{CC} (V) M 4.5 5.5 4.5		22	33	_	41		
			50	4.5	_	17	30	_	38		
Output enable time	t_{pZL}	$R_L = 1 \text{ k}\Omega$	30	5.5		14	25	_	31	ns	
Output enable time	t _{pZH}		150	4.5		25	38	_	48	115	
				130	5.5		19	33	_	41	
Output disable time	t_{pLZ}	t_{pLZ} $R_{\text{L}} = 1 \text{ k}\Omega$	50	4.5	_	16	28	_	35	ns	
Output disable time	t _{pHZ}	TV 1 K22	30	5.5		14	24	_	30	110	
Maximum clock	f _{max}		50	4.5	31	50		25	_	MHz	
frequency	ımax	_	30	5.5	37	59	_	30	_	IVII IZ	
Input capacitance	C _{IN}	_	_		_	5	10	_	10	pF	
Output capacitance	Cout	_	-		1	10	_	_	_	pF	
Power dissipation	C _{PD}					48				ηE	
capacitance	(Note)	_	_			40				pF	

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

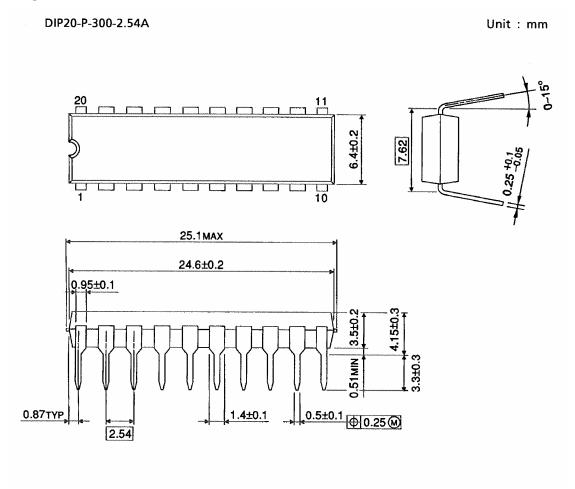
$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per F/F)

And the total C_{PD} when n pcs. of flip flop operate can be gained by the following equation:

4

$$C_{PD}$$
 (total) = 30 + 18 · n

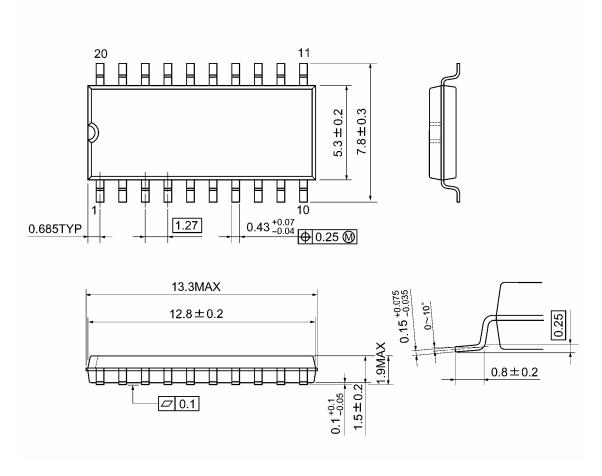
Package Dimensions



Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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